QUICKSWITCH® PRODUCTS HIGH-SPEED CMOS 24-BIT BUS SWITCH

IDTQS316211

FEATURES:

- Enhanced N channel FET with no inherent diode to Vcc
- 5Ω bidirectional switches connect inputs to outputs
- Zero propagation delay, zero ground bounce
- TTL-compatible input and output levels
- Undershoot clamp diodes on all switch and control pins
- Available in 56-pin SSOP and TSSOP Packages

APPLICATIONS

- Hot-swapping, hot-docking
- Voltage translation (5V to 3.3V)
- Logic replacement (data processing)
- Power conservation
- Capacitance reduction and isolation
- Bus isolation
- Clock gating

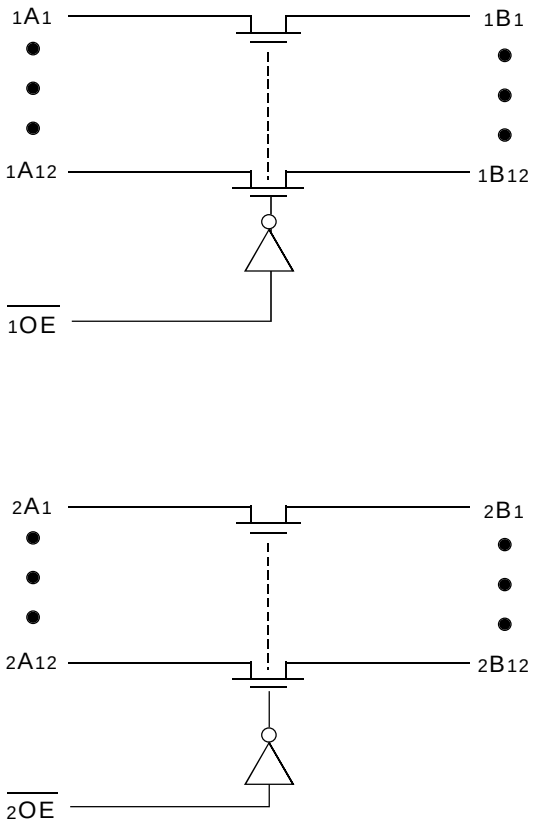
DESCRIPTION:

The QS316211 provides a set of 24 high-speed CMOS TTL-compatible bus switches. The low ON resistance of the QS316211 allows inputs to be connected to outputs without adding propagation delay and without generating additional ground bounce noise. The device operates as a 24-bit bus switch. When $\overline{1OE}$ is low, 1An is connected to 1Bn. When $\overline{2OE}$ is low, 2An is connected to 2Bn.

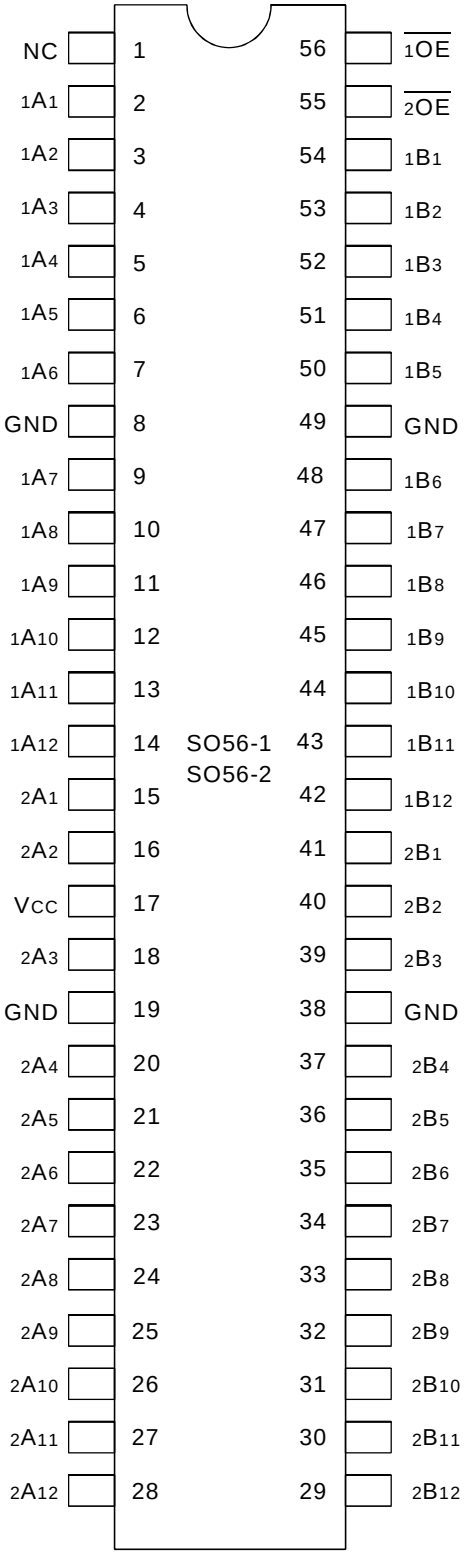
The QS316211 is ideal for switching wide digital buses, 5V to 3.3V translation, and for hot plug buffering.

The QS316211 is characterized for operation at -40°C to +85°C.

FUNCTIONAL BLOCK DIAGRAM



PIN CONFIGURATION



SSOP/ TSSOP
TOP VIEW

ABSOLUTE MAXIMUM RATINGS (1)

Symbol	Description	Max.	Unit
V_{TERM}(2)	Supply Voltage to Ground	– 0.5 to +7	V
V_{TERM}(3)	DC Switch Voltage V_S	– 0.5 to +7	V
V_{TERM}(3)	DC Input Voltage V_{IN}	– 0.5 to +7	V
V_{AC}	AC Input Voltage (pulse width ≤20ns)	-3	V
I_{OUT}	DC Output Current	120	mA
P_{MAX}	Maximum Power Dissipation (T_A = 85°C)	.93	W
T_{STG}	Storage Temperature	– 65 to +150	°C

NOTES:
1. Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.
2. Vcc Terminals.
3. All terminals except Vcc.

CAPACITANCE

(T_A = +25°C, f = 1.0MHz, V_{IN} = 0V, V_{OUT} = 0V)

Pins	Typ.	Max. (1)	Unit
Control Inputs	4.5	6	pF
Quickswitch Channels (Switch OFF)	5.5	7	pF

NOTE:
1. This parameter is guaranteed but not production tested.

PIN DESCRIPTION

Pin Names	I/O	Description
xA_1 - xA_{12}	I/O	Bus A
xB_1 - xB_{12}	I/O	Bus B
$\overline{1OE}$ - $\overline{2OE}$	I	Data Select

FUNCTION TABLE(1)

$\overline{1OE}$	$\overline{2OE}$	1An	2An	Function
L	L	$_1$Bn	$_2$Bn	$_1$An to $_1$Bn, $_2$An to $_2$Bn
L	H	$_1$Bn	Z	$_1$An to $_1$Bn
H	L	Z	$_2$Bn	$_2$An to $_2$Bn
H	H	Z	Z	Disconnect

NOTE:
1. H = HIGH Voltage Level
   L = LOW Voltage Level
   Z = High-Impedence

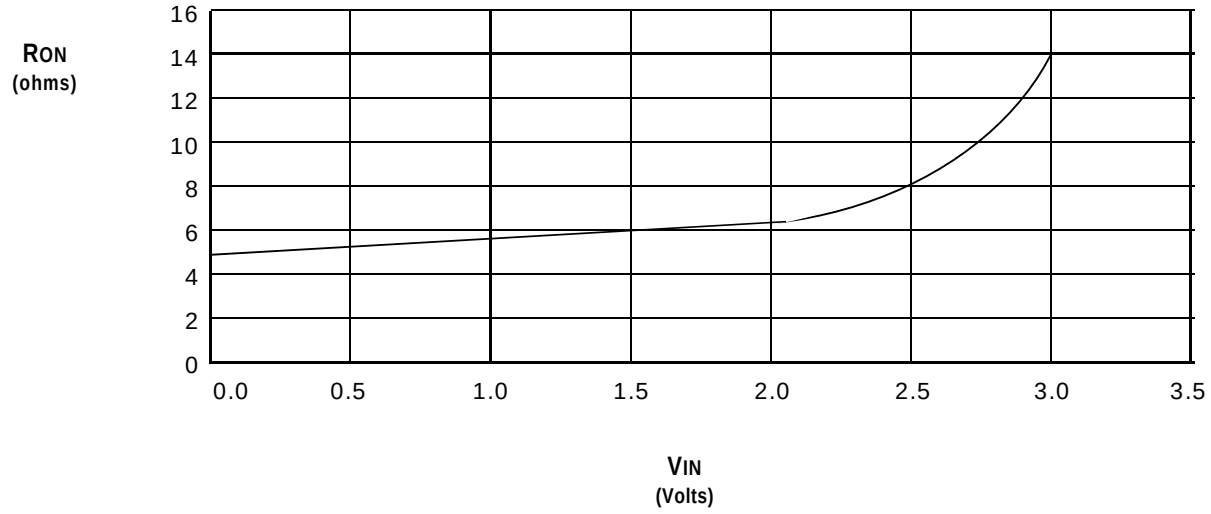
DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:
Industrial: T_A = -40°C to +85°C, V_{CC} = 5.0V ± 10%

Symbol	Parameter	Test Conditions	Min.	Typ.(1)	Max.	Unit
V_{IH}	Input HIGH Voltage	Guaranteed Logic HIGH for Control Pins	2	—	—	V
V_{IL}	Input LOW Voltage	Guaranteed Logic LOW for Control Pins	—	—	0.8	V
I_{IN}	Input Leakage Current (Control Inputs)	$0V \le V_{IN} \le Vcc$	—	0.01	±1	µA
I_{OZ}	Off-State Current (Hi-Z)	$0V \le V_{OUT} \le Vcc$, Switches OFF	—	0.01	±1	µA
R_{ON}	Switch ON Resistance	Vcc = Min., V_{IN} = 0V, I_{ON} = 30mA	—	5	7	Ω
R_{ON}	Switch ON Resistance	Vcc = Min., V_{IN} = 2.4V, I_{ON} = 15mA	—	10	12	Ω
V_P	Pass Voltage (2)	V_{IN} = Vcc = 5V, I_{OUT} = -5µA	3.7	4	4.2	V

NOTES:
1. Typical values are at V_{CC} = 5.0V, T_A = 25°C.
2. Pass voltage is guaranteed but not production tested.

TYPICAL ON RESISTANCE vs V_{IN} AT V_{CC} = 5V



POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions[1]	Max.	Unit
I_{CCQ}	Quiescent Power Supply Current	V_{CC} = Max., V_{IN} = GND or Vcc, f = 0	3	µA
ΔI_{CC}	Power Supply Current per Control Input HIGH [2]	V_{CC} = Max., V_{IN} = 3.4V, f = 0	2.5	mA
I_{CCD}	Dynamic Power Supply Current per MHz[3]	V_{CC} = Max., A and B pins open Control Input Toggling at 50% Duty Cycle	0.25	mA/MHz

NOTES:
1. For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.
2. Per TLL driven input (V_{IN} = 3.4V). A and B pins do not contribute to ΔI_{CC}.
3. This current applies to the control inputs only and represents the current required to switch internal capacitance at the specified frequency. The A and B inputs generate no significant AC or DC currents as they transition. This parameter is guaranteed but not production tested.

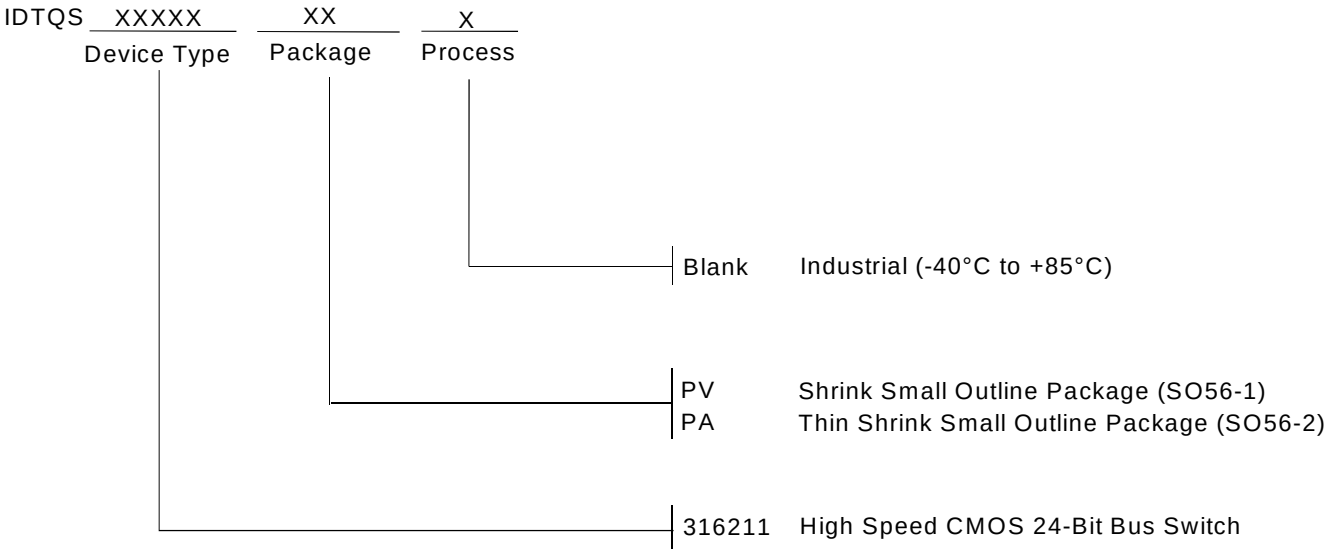
SWITCHING CHARACTERISTICS OVER OPERATING RANGE

T_A = -40°C to +85°C, V_{CC} = 5.0V ± 10%
C_{LOAD} = 50pF, R_{LOAD} = 500Ω unless otherwise noted.

Symbol	Parameter	Min. [1]	Typ.	Max.	Unit
t_{PLH} t_{PHL}	Data Propagation Delay [2,3] xAn to xBn, xBn to xAn	—	—	0.25 [3]	ns
t_{PZL} t_{PZH}	Switch Turn-on Delay $\overline{nOE}$ to xAn, xBn	1.5	—	6.5	ns
t_{PLZ} t_{PHZ}	Switch Turn-off Delay [2] $\overline{nOE}$ to xAn, xBn	1.5	—	6.2	ns

NOTES:
1. Minimums are guaranteed but not production tested.
2. This parameter is guaranteed but not production tested.
3. The time constant for the switch alone is of the order of 0.25ns for C_L = 50pF. The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

ORDERING INFORMATION



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